

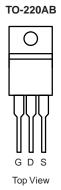
## N-Channel 100-V (D-S) MOSFET

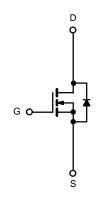
PRODUCT	SUMMARY	
V <sub>(BR)DSS</sub> (V)	r <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
100	0.032 at V <sub>GS</sub> = 10 V	45
	0.035 at V <sub>GS</sub> = 4.5 V	40

#### FEATURES

- TrenchFET<sup>®</sup> Power MOSFETS
- 175 °C Junction Temperature
- Low Thermal Resistance Package







N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_{C} = 25 \text{ °C}$ , unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	100	v	
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
Continuous Drain Current ( $T_1 = 175 ^{\circ}C$ )	T <sub>C</sub> = 25 °C	1-	45		
Continuous Drain Current (1j = 175 C)	T <sub>C</sub> = 125 °C	I <sub>D</sub>	30		
Pulsed Drain Current		I <sub>DM</sub>	135	A	
Avalanche Current		I <sub>AR</sub>	35	1	
Repetitive Avalanche Energy <sup>a</sup>	L = 0.1 mH	E <sub>AR</sub>	61	mJ	
Maximum Power Dissipation <sup>a</sup>	T <sub>C</sub> = 25 °C	р	127 <sup>b</sup>	14/	
	T <sub>A</sub> = 25 °C <sup>c</sup>	– P <sub>D</sub> –	3.75	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS	5			
Parameter		Symbol	Limit	Unit
Junction-to-Ambient	(PCB Mount) <sup>c</sup>	R <sub>thJA</sub>	40	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	1.4	5

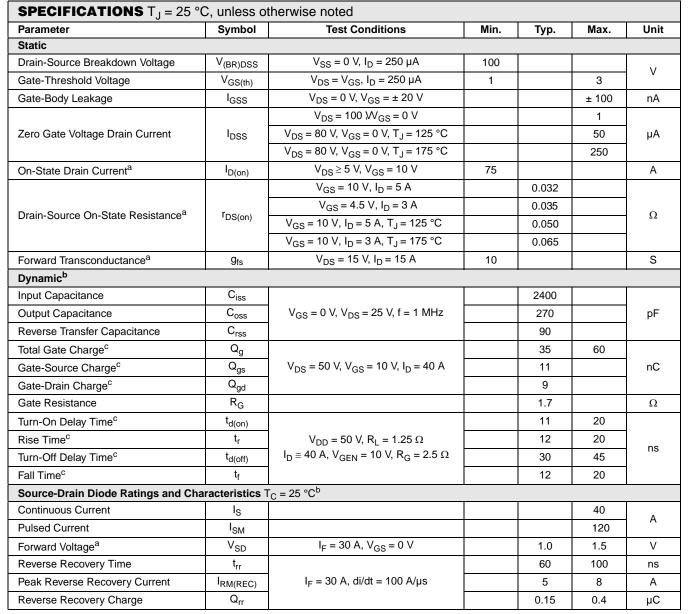
Notes:

a. Duty cycle  $\leq$  1 %.

b. See SOA curve for voltage derating.

c. When Mounted on 1" square PCB (FR-4 material).

\* Pb containing terminations are not RoHS compliant, exemptions may apply.



Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing.

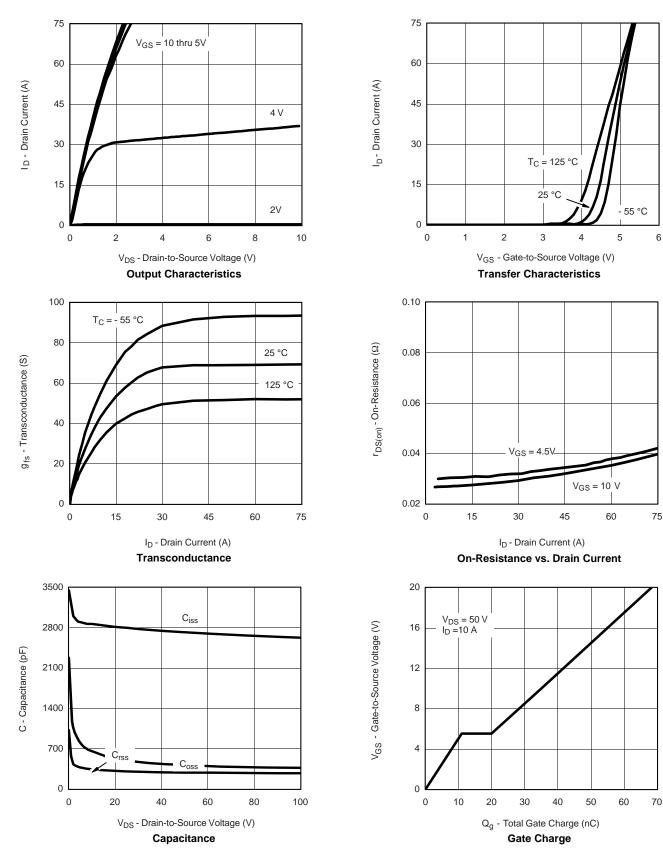
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



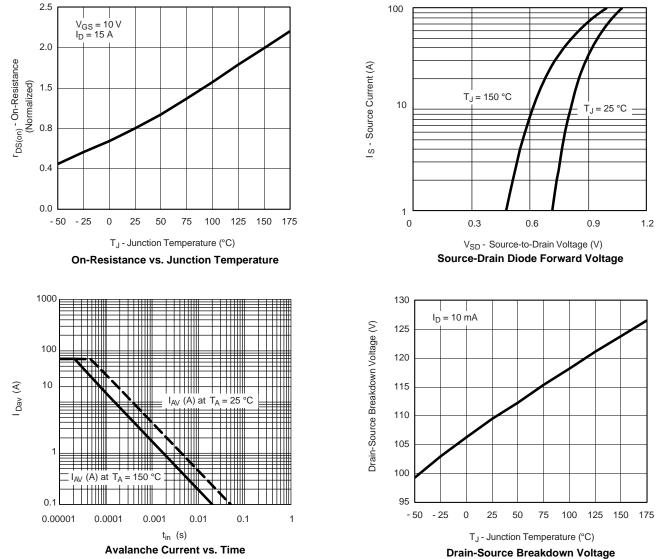
6

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





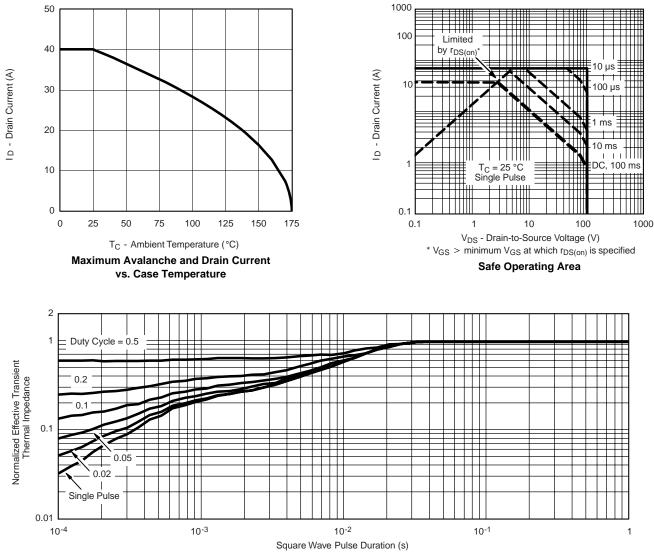
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vs. Junction Temperature



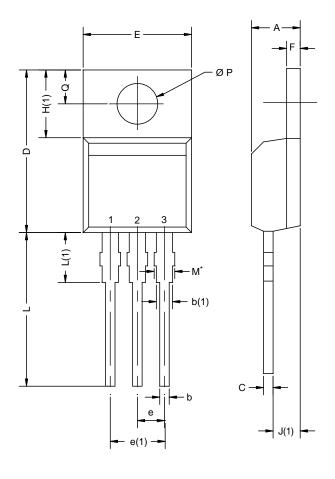
#### THERMAL RATINGS



Normalized Thermal Transient Impedance, Junction-to-Case



## **TO-220AB**



	MILLIN	IETERS	INC	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.		
А	4.25	4.65	0.167	0.183		
b	0.69	1.01	0.027	0.040		
b(1)	1.20	1.73	0.047	0.068		
С	0.36	0.61	0.014	0.024		
D	14.85	15.49	0.585	0.610		
Е	10.04	10.51	0.395	0.414		
е	2.41	2.67	0.095	0.105		
e(1)	4.88	5.28	0.192	0.208		
F	1.14	1.40	0.045	0.055		
H(1)	6.09	6.48	0.240	0.255		
J(1)	2.41	2.92	0.095	0.115		
L	13.35	14.02	0.526	0.552		
L(1)	3.32	3.82	0.131	0.150		
ØР	3.54	3.94	0.139	0.155		
Q	2.60	3.00	0.102	0.118		
ECN: X12- DWG: 547	0208-Rev. N, 1	08-Oct-12				

#### Notes

 $^{\star}$  M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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